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April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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EOL announced Product

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HAT3005R

Silicon N/P Channel Power MOS FET
High Speed Power Switching

REJ03G0366-0300

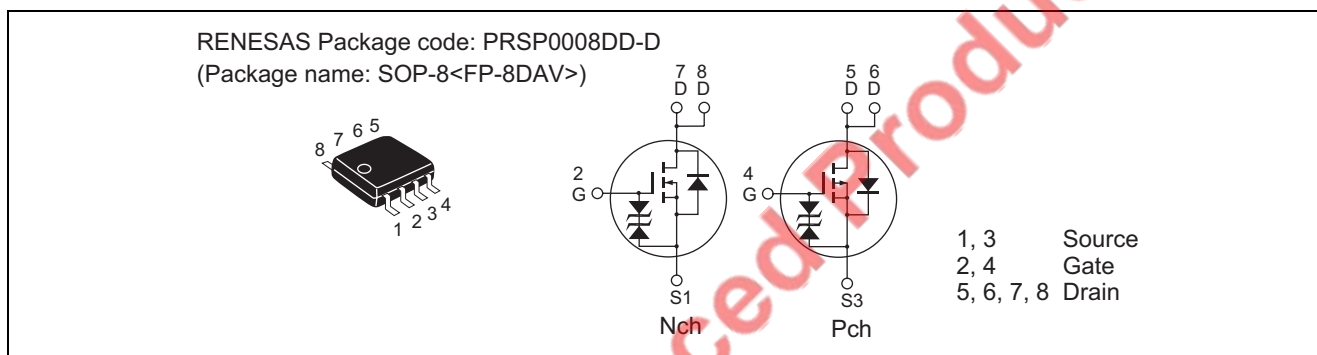
Rev.3.00

Jun. 10, 2005

Features

- Low on-resistance
- Capable of 4 V gate drive
- Low drive current
- High density mounting

Outline



Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings		Unit
		Nch	Pch	
Drain to source voltage	V_{DSS}	150	-150	V
Gate to source voltage	V_{GSS}	±15	±15	V
Drain current	I_D	0.5	-0.25	A
Drain peak current	$I_{D(pulse)}$ ^{Note1}	2	-1	A
Body-drain diode reverse drain current	I_{DR}	0.5	-0.25	A
Channel dissipation	Pch ^{Note2}	1		W
Channel dissipation	Pch ^{Note3}	1.5		W
Channel temperature	Tch	150		°C
Storage temperature	Tstg	-55 to +150		°C

Notes: 1. $PW \leq 10 \mu s$, duty cycle $\leq 1 \%$

2. 1 Drive operation : When using the glass epoxy board (FR4 40 x 40 x 1.6 mm)

3. 2 Drive operation : When using the glass epoxy board (FR4 40 x 40 x 1.6 mm)

Electrical Characteristics

• N channel

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	150	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	± 15	—	—	V	$I_G = \pm 100 \mu\text{A}, V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	5	μA	$V_{DS} = 150 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	—	2.1	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	1.6	2.2	Ω	$I_D = 0.5 \text{ A}, V_{GS} = 10 \text{ V}$ ^{Note4}
	$R_{DS(on)}$	—	1.9	2.7	Ω	$I_D = 0.5 \text{ A}, V_{GS} = 4 \text{ V}$ ^{Note4}
	$R_{DS(on)}$	—	2.4	5.5	Ω	$I_D = 2 \text{ A}, V_{GS} = 5 \text{ V}$ ^{Note4}
Forward transfer admittance	$ y_{fs} $	0.56	0.86	—	S	$I_D = 0.5 \text{ A}, V_{DS} = 10 \text{ V}$ ^{Note4}
Input capacitance	C_{iss}	—	95	—	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	42	—	pF	
Reverse transfer capacitance	C_{rss}	—	11	—	pF	
Turn-on delay time	$t_{d(on)}$	—	9	—	ns	
Rise time	t_r	—	16	—	ns	$V_{DD} \cong 30 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	18	—	ns	
Fall time	t_f	—	14	—	ns	
Body-drain diode forward voltage	V_{DF}	—	0.9	1.4	V	$I_F = 0.5 \text{ A}, V_{GS} = 0$ ^{Note4}
Body-drain diode reverse recovery time	t_{rr}	—	90	—	ns	$I_F = 0.5 \text{ A}, V_{GS} = 0$ $diF/dt = 50 \text{ A}/\mu\text{s}$

Notes: 4. Pulse test

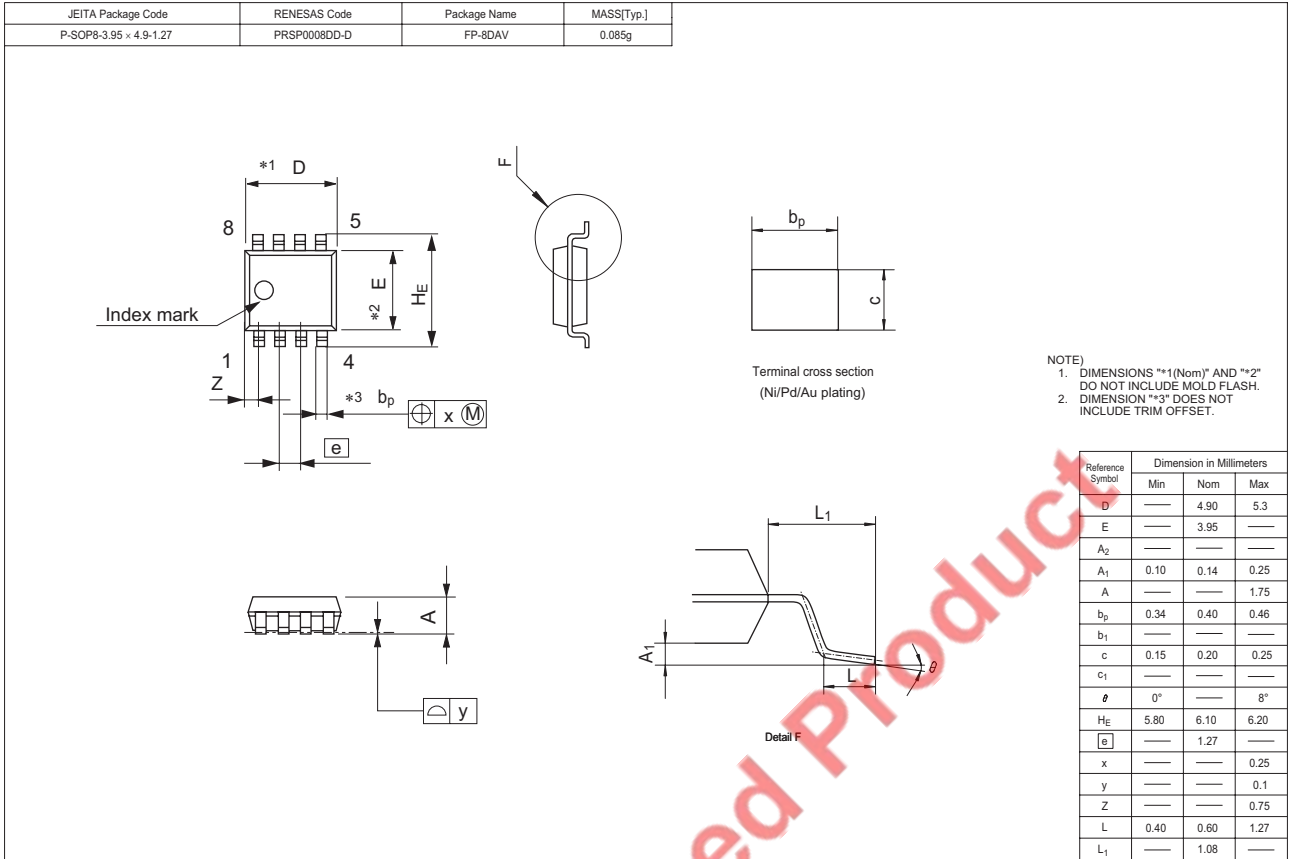
• P channel

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-150	—	—	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	± 15	—	—	V	$I_G = \pm 100 \mu\text{A}, V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	-5	μA	$V_{DS} = -150 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0	—	-2.0	V	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	5.0	6.2	Ω	$I_D = -0.25 \text{ A}, V_{GS} = -10 \text{ V}$ ^{Note5}
	$R_{DS(on)}$	—	6.0	7.5	Ω	$I_D = -0.25 \text{ A}, V_{GS} = -4 \text{ V}$ ^{Note5}
	$R_{DS(on)}$	—	7.0	10.0	Ω	$I_D = -1 \text{ A}, V_{GS} = -5 \text{ V}$ ^{Note5}
Forward transfer admittance	$ y_{fs} $	0.29	0.45	—	S	$I_D = -0.25 \text{ A}, V_{DS} = -10 \text{ V}$ ^{Note5}
Input capacitance	C_{iss}	—	92	—	pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0,$ $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	37	—	pF	
Reverse transfer capacitance	C_{rss}	—	10	—	pF	
Turn-on delay time	$t_{d(on)}$	—	10	—	ns	
Rise time	t_r	—	13	—	ns	$V_{DD} \cong -30 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	22	—	ns	
Fall time	t_f	—	15	—	ns	
Body-drain diode forward voltage	V_{DF}	—	-0.9	-1.4	V	$I_F = -0.25 \text{ A}, V_{GS} = 0$ ^{Note5}
Body-drain diode reverse recovery time	t_{rr}	—	80	—	ns	$I_F = -0.25 \text{ A}, V_{GS} = 0$ $diF/dt = 50 \text{ A}/\mu\text{s}$

Notes: 5. Pulse test

Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
HAT3005R-EL-E	2500 pcs.	Taping

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